

# Surface Mount Schottky Power Rectifier Pb-Free package is available

The LMBR0530T1G uses the Schottky Barrier principle with a large area metal-to-silicon power diode. Ideally suited for low voltage, high frequency rectification or as free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system. This package also provides an easy to work with alternative to leadless 34 package style. These state-of-the-artdevices have the following features:

#### **Features**

- Guardring for Stress Protection
- Low Forward Voltage
- 125°C Operating Junction Temperature
- Epoxy Meets UL 94, V-0 @ 0.125 in
- Package Designed for Optimal Automated Board Assembly
- Pb-Free Packages are Available

#### **Mechanical Characteristics**

- Reel Options: LMBR0530T1G= 3,000 per 7 in reel/8 mm tape LMBR0530T3G= 10,000 per 13 in reel/8 mm tape
- Device Marking:B3
- Polarity Designator: Cathode Band
- Weight: 11.7 mg (approximately)
- Case: Epoxy, Molded
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

## **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	30	V
Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>L</sub> = 100°C)	I <sub>F(AV)</sub>	0.5	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	5.5	А
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Operating Junction Temperature	$T_J$	-65 to +125	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	1000	V/μs
ESD Rating: Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# LMBR0530T1G



#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>	
LMBR0530T1G	SOD-123 (Pb-Free)	3000/Tape & Reel	
LMBR0530T3G	SOD-123 (Pb-Free)	10,000/Tape & Reel	



# LMBR0530T1G

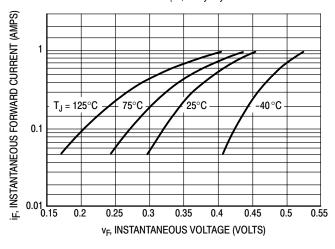
#### THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance – Junction–to–Ambient (Note 1)	$R_{\theta JA}$	206	°C/W
Thermal Resistance – Junction–to–Lead	$R_{ heta JL}$	150	°C/W

#### **ELECTRICAL CHARACTERISTICS**

Minimum Reverse Breakdown Voltage $(i_R = 130 \ \mu A)$	V <sub>(BR)R</sub>	30	V
Maximum Instantaneous Forward Voltage (Note 2) ( $i_F = 0.1 \text{ Amps}, T_J = 25^{\circ}\text{C}$ ) ( $i_F = 0.5 \text{ Amps}, T_J = 25^{\circ}\text{C}$ )	v <sub>F</sub>	0.375 0.45	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C = 25^{\circ}C$ ) ( $V_R = 15 \text{ V}, T_C = 25^{\circ}C$ )	I <sub>R</sub>	130 20	μА

- 1. 1 inch square pad size (1 x 0.5 inch for each lead) on FR4 board. 2. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2%.



10<sup>4</sup> R, REVERSE CURRENT (μA)  $T_J = 125^{\circ}C$ 1000 100 75°C 10 25°C 5 10 20 25 30 35 40 V<sub>R</sub>, REVERSE VOLTAGE (VOLTS)

Figure 1. Typical Forward Voltage

**Figure 2. Typical Reverse Current** 

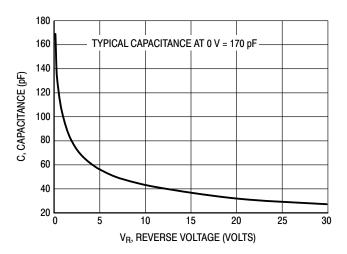


Figure 3. Typical Capacitance



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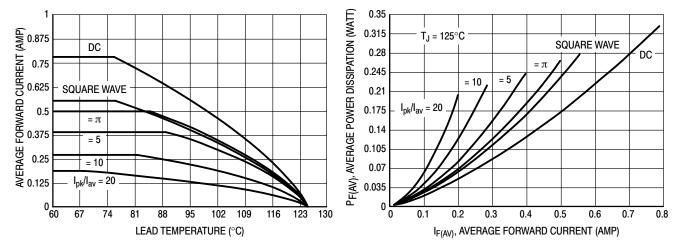


Figure 4. Current Derating (Lead)

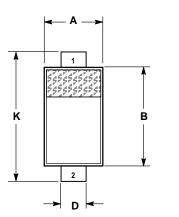
Figure 5. Power Dissipation

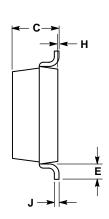


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# **PACKAGE DIMENSIONS**

## SOD-123





#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.055	0.071	1.40	1.80
В	0.100	0.112	2.55	2.85
С	0.037	0.053	0.95	1.35
D	0.020	0.028	0.50	0.70
Е	0.004		0.25	
Н	0.000	0.004	0.00	0.10
J		0.006		0.15
K	0.140	0.152	3.55	3.85

STYLE 1: PIN 1. CATHODE 2. ANODE

# **RECOMMENDED FOOTPRINT FOR SOD-123**

